



# KA1M0265R/KA1H0265R Fairchild Power Switch(FPS)

#### Features

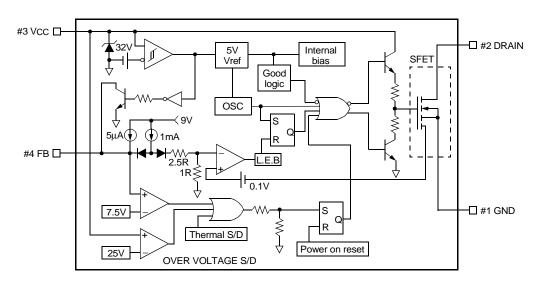
- Precision Fixed Operating Frequency
- KA1M0265R (70kHz), KA1H0265R (100kHz)
- Pulse by Pulse Over Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 23V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto Restart

#### Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. compared to discrete MOSFET and controller or RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.



#### Internal Block Diagram



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#### **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit	
Maximum Drain Voltage <sup>(1)</sup>	Vd,max	650	V	
Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)	Vdgr	650	V	
Gate-Source (GND) Voltage	VGS	±30	V	
Drain Current Pulsed <sup>(2)</sup>	IDM	8.0	ADC	
Single Pulsed Avalanche Energy <sup>(3)</sup>	EAS	68	mJ	
Continuous Drain Current (Tc=25°C)	ID	2.0	ADC	
Continuous Drain Current (T <sub>C</sub> =100°C)	۱ <sub>D</sub>	1.3	ADC	
Maximum Supply Voltage	VCC,MAX	30	V	
Input Voltage Range	VFB	-0.3 to V <sub>SD</sub>	V	
Total Bower Dissinction	PD	42	W	
Total Power Dissipation	Darting	0.33	W/°C	
Operating Ambient Temperature	TA	-25 to +85	°C	
Storage Temperature	TSTG	-55 to +150	٥°C	

Notes:

1. Tj = 25°C to 150°C

2. Repetitive rating: Pulse width limited by maximum junction temperature

3. L = 51mH, V\_DD = 50V, R\_G = 25 \Omega, starting T\_j = 25 ^{\circ}C

## **Electrical Characteristics (SFET part)**

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50µA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max., Rating, VGS=0V	-	-	50	μΑ
		V <sub>DS</sub> =0.8Max., Rating, V <sub>GS</sub> =0V, T <sub>C</sub> =125°C	-	-	200	μΑ
Static Drain-Source on Resistance (Note)	RDS(ON)	VGS=10V, ID=1.0A	-	5.0	6.0	Ω
Forward Transconductance (Note)	gfs	VDS=50V, ID=1.0A	1.5	2.5	-	S
Input Capacitance	Ciss		-	550	-	
Output Capacitance	Coss	VGS=0V, VDS=25V, f=1MHz	-	38	-	pF
Reverse Transfer Capacitance	Crss		-	17	-	
Turn on Delay Time	td(on)	V <sub>DD</sub> =0.5BV <sub>DSS</sub> , I <sub>D</sub> =2.0A	-	20	-	
Rise Time	tr	(MOSFET switching	-	15	-	nS
Turn Off Delay Time	td(off)	time are essentially independent of	-	55	-	115
Fall Time	tf	operating temperature)	-	25	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=2.0A, VDS=0.5BVDSS (MOSFET	-	-	35	
Gate-Source Charge	Qgs	switching time are	-	3	-	nC
Gate Drain (Miller) Charge	Qgd	essentially independent of operating temperature)	-	12	-	

Note:

1. Pulse test: Pulse width  $\leq 300\mu S$ , duty cycle  $\leq 2\%$ 

 $2. S = \frac{1}{R}$ 

## Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit	
UVLO SECTION							
Start Threshold Voltage	VSTART	-	14	15	16	V	
Stop Threshold Voltage	VSTOP	After turn on	9	10	11	V	
OSCILLATOR SECTION							
Initial Accuracy	Fosc	KA1M0265R	61	67	73	- kHz	
		KA1H0265R	90	100	110		
Frequency Change With Temperature <sup>(2)</sup>	$\Delta F / \Delta T$	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%	
	Dmax	KA1M0265R	74	77	80	0/	
Maximum Duty Cycle	Dmax	KA1H0265R	64	67	70	%	
FEEDBACK SECTION						•	
Feedback Source Current	IFB	Ta=25°C, $0V \le Vfb \le 3V$	0.7	0.9	1.1	mA	
Shutdown Feedback Voltage	VSD	-	6.9	7.5	8.1	V	
Shutdown Delay Current	Idelay	Ta=25°C, 5V $\leq$ Vfb $\leq$ VsD	4.0	5.0	6.0	μA	
REFERENCE SECTION							
Output Voltage <sup>(1)</sup>	Vref	Ta=25°C	4.80	5.00	5.20	V	
Temperature Stability <sup>(1)(2)</sup>	Vref/∆T	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C	
CURRENT LIMIT (SELF-PROTECTION) SECTION							
Peak Current Limit	IOVER	Max. inductor current	1.05	1.2	1.35	Α	
PROTECTION SECTION							
Thermal Shutdown Temperature (Tj) <sup>(1)</sup>	T <sub>SD</sub>	-	140	160	-	°C	
Over Voltage Protection Voltage	Vovp	-	23	25	28	V	
TOTAL DEVICE SECTION							
Start-Up Current	ISTART	VCC=14V	0.1	0.3	0.4	mA	
Operating Supply Current (Control Part Only)	IOP	Ta=25°C	6	12	18	mA	
VCC Zener Voltage	Vz	ICC=20mA	30	32.5	35	V	

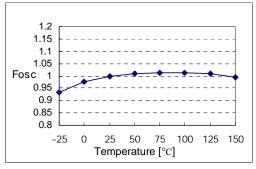
Note:

1. These parameters, although guaranteed, are not 100% tested in production

2. These parameters, although guaranteed, are tested in EDS (wafer test) process

#### **Typical Performance Characteristics**

(These characteristic graphs are normalized at Ta=25°C)



**Figure 1. Operating Frequency** 

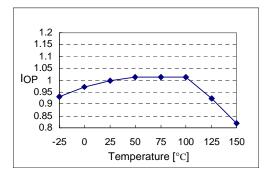


Figure 3. Operating Supply Current

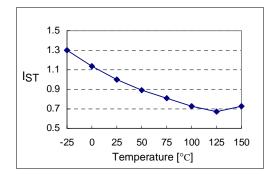


Figure 5. Start up Current

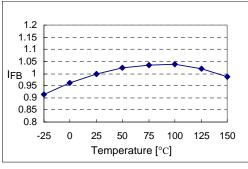


Figure 2. Feedback Source Current

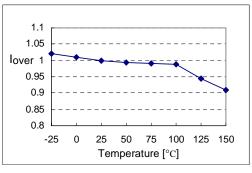


Figure 4. Peak Current Limit

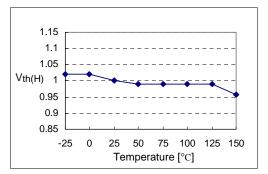


Figure 6. Start Threshold Voltage

#### Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

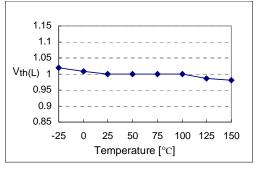


Figure 7. Stop Threshold Voltage

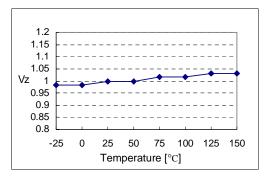


Figure 9. Vcc Zener Voltage

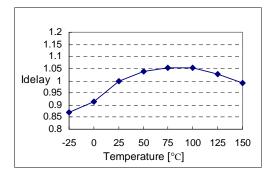


Figure 11. Shutdown Delay Current

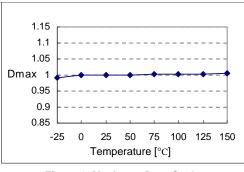


Figure 8. Maximum Duty Cycle

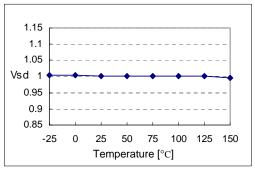


Figure 10. Shutdown Feedback Voltage

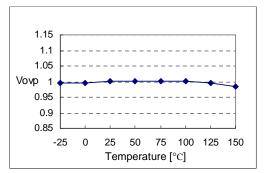


Figure 12. Over Voltage Protection

#### Typical Performance Characteristics (Continued)

(These characteristic groups are normalized at Ta=25°C)

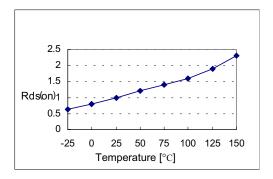
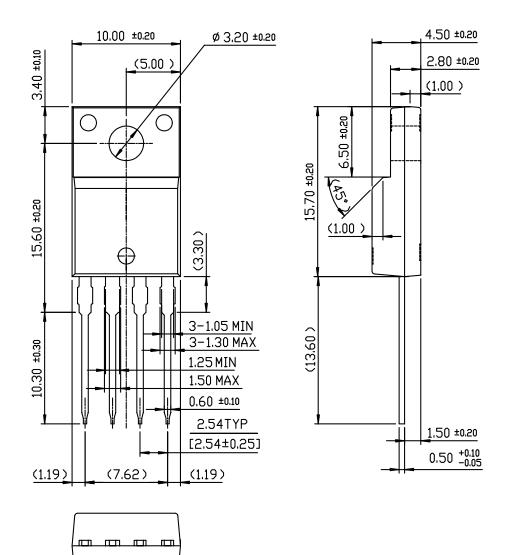


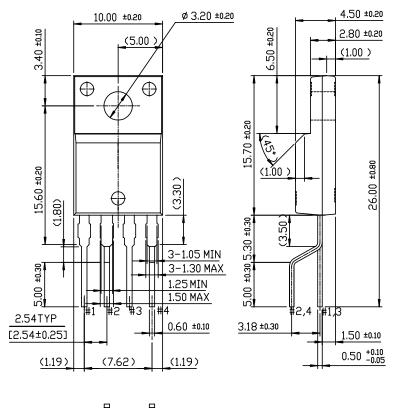
Figure 13. Static Drain-Source on Resistance

#### **Package Dimensions**



TO-220F-4L

## TO-220F-4L(Forming)



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#### **Ordering Information**

Product Number	Package	Rating	Fosc	
KA1M0265R-TU	TO-220F-4L	650V. 2A	67kHz	
KA1M0265R-YDTU	TO-220F-4L(Forming)	030V, ZA	07 KHZ	
KA1H0265R-TU	TO-220F-4L			
KA1H0265R-YDTU	TO-220F-4L(Forming)	030V, ZA	100kHz	

TU : Non Forming Type YDTU : Forming Type

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